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MEMC 00-1400 (2806.1)
PATENT



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of Robert J. Falster et al.
Serial No. 10/039,196
Filed January 2, 2002
Confirmation No. 7221

Art Unit 1772

For PROCESS FOR PREPARING SINGLE CRYSTAL SILICON HAVING
IMPROVED GATE OXIDE INTEGRITY

Examiner Rhee, Jane J.

March 18, 2005

RULE 1.312 AMENDMENT

TO THE COMMISSIONER FOR PATENTS,

SIR:

Please enter the following amendment into the record of this case under the provisions of Rule 1.312.

Amendment to Specification begins on page 2.

Remarks begin on page 3.